

12/7/2009

PRODUCT RELIABILITY REPORT FOR

MAXQ61H, Rev A2

Maxim Integrated Products

4401 South Beltwood Parkway Dallas, TX 75244-3292

Prepared by:

Don Lipps Manager, Reliability Engineering Maxim Integrated Products 4401 South Beltwood Pkwy. Dallas, TX 75244-3292 Email: don.lipps@maxim-ic.com ph: 972-371-3739 fax: 972-371-6016

Conclusion:

The following qualification successfully meets the quality and reliability standards required of all Maxim products:

MAXQ61H, Rev A2

In addition, Maxim's continuous reliability monitor program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards. The current status of the reliability monitor program can be viewed at http://www.maxim-ic.com/TechSupport /dsreliability.html.

Device Description:

A description of this device can be found in the product data sheet. You can find the product data sheet at http://dbserv.maxim-ic.com/l_datasheet3.cfm.

Reliability Derating:

The Arrhenius model will be used to determine the acceleration factor for failure mechanisms that are temperature accelerated.

AfT = exp((Ea/k)*(1/Tu - 1/Ts)) = tu/ts AfT = Acceleration factor due to Temperature tu = Time at use temperature (e.g. 55°C) ts = Time at stress temperature (e.g. 125°C) k = Boltzmann's Constant (8.617 x 10-5 eV/°K) Tu = Temperature at Use (°K) Ts = Temperature at Stress (°K) Ea = Activation Energy (e.g. 0.7 ev)

The activation energy of the failure mechanism is derived from either internal studies or industry accepted standards, or activation energy of 0.7ev will be used whenever actual failure mechanisms or their activation energies are unknown. All deratings will be done from the stress ambient temperature to the use ambient temperature.

An exponential model will be used to determine the acceleration factor for failure mechanisms, which are voltage accelerated.

AfV = exp(B*(Vs - Vu)) AfV = Acceleration factor due to Voltage Vs = Stress Voltage (e.g. 7.0 volts) Vu = Maximum Operating Voltage (e.g. 5.5 volts) B = Constant related to failure mechanism type (e.g. 1.0, 2.4, 2.7, etc.)

The Constant, B, related to the failure mechanism is derived from either internal studies or industry accepted standards, or a B of 1.0 will be used whenever actual failure mechanisms or their B are unknown. All deratings will be done from the stress voltage to the maximum operating voltage. Failure rate data from the operating life test is reported using a Chi-Squared statistical model at the 60% or 90% confidence level (Cf).

The failure rate, Fr, is related to the acceleration during life test by:

Fr = X/(ts * AfV * AfT * N * 2)X = Chi-Sq statistical upper limit N = Life test sample size Failure Rates are reported in FITs (Failures in Time) or MTTF (Mean Time To Failure). The FIT rate is related to MTTF by:

MTTF = 1/Fr

NOTE: MTTF is frequently used interchangeably with MTBF.

The calculated failure rate for this device/process is:

FA	ILURE RATE:	M	FTF (YRS):	40473		FITS:	2.8			
		AILS:	0							
Only data from Operating Life or similar stresses are used for this calculation.										
The parameters used to calculate this failure rate are as follows:										
Cf	: 60%	Ea: 0.7	B: 0	Tu:	25	°C	Vu: 3.6	Volts		

The reliability data follows. At the start of this data is the device information. The next section is the detailed reliability data for each stress. The reliability data section includes the latest data available and may contain some generic data. **Bold** Product Number denotes specific product data.

Device Information	on:										
Process:		TSMC 0.18um Mixed signal, Embedded Flash, General Purpose, Two Poly Five Metal, 1.8V/3.3V Polyimide - No									
Passivation:		SiO/SiN									
Die Size:	59 x 57	59 x 57									
Number of Tran											
Interconnect: Gate Oxide Thickness:		Aluminur 32 Å	Aluminum / 0.5% Copper								
Gate Oxide Thic	kness:	32 A									
ESD HBM											
DESCRIPTION	DATE	CODE/PRODUC	T/LOT	CONDITION	RE/	DPOIN	QTY	FAILS	FA#		
ESD SENSITIVITY	0906	MAXQ61H	QJ091049AB	JESD22-A114 HBM 500 VOLTS	1	PUL'S	3	0			
ESD SENSITIVITY	0906	MAXQ61H	QJ091049AB	JESD22-A114 HBM 1000 VOLTS	1	PUL'S	3	0			
ESD SENSITIVITY	0906	MAXQ61H	QJ091049AB	JESD22-A114 HBM 2000 VOLTS	1	PUL'S	3	0			
ESD SENSITIVITY	0906	MAXQ61H	QJ091049AB	JESD22-A114 HBM 3000 VOLTS	1	PUL'S	3	0			
ESD SENSITIVITY	0906	MAXQ61H	QJ091049AB	JESD22-A114 HBM 4000 VOLTS	1	PUL'S	3	0			
					Total:			0			
LATCH-UP											
DESCRIPTION	DATE	CODE/PRODUC	T/LOT	CONDITION	REA	DPOIN	QTY	FAILS	FA#		
LATCH-UP I	0906	MAXQ61H	QJ091049AB	JESD78A, I-TEST 125C			6	0			
LATCH-UP V	0906	MAXQ61H	QJ091049AB	JESD78A, V-SUPPLY TEST 125C			6	0			
					Tota	d:		0			
OPERATING LIFE											
DESCRIPTION	DATE	CODE/PRODUC	T/LOT	CONDITION	RE/	DPOIN	QTY	FAILS	FA#		

Rev B, 1/3/08

HIGH TEMP OP LIFE	0814	MAXQ1103	QN089294AA	125C, 3 (PSB)	8.6V (PSA) & 2	2.0V	1000	HRS	77	0
HIGH TEMP OP LIFE	0828	MAXQ2010	QK086138CA	125C, 3	3.6 VOLTS		1000	HRS	76	0
HIGH TEMP OP LIFE	0837	MAX2990	QN096322AB	125C, 3 (PSB)	8.6V (PSA) & 2	2.0V	1000	HRS	77	0
HIGH TEMP OP LIFE	0851	MAXQ3108	QJ091011AC	125C, 3	8.6 VOLTS		192	HRS	73	0
HIGH TEMP OP LIFE	0851	MAXQ610	QJ091123AB	125C, 3 (PSB)	8.6V (PSA) & 2	2.0V	1000	HRS	77	0
HIGH TEMP OP LIFE	0906	MAXQ61H	QJ091049AB	125C, 3	3.6 VOLTS		192	HRS	45	0
HIGH TEMP OP LIFE	0909	MAXQ8913	NQQ8ZAD	125C, 3 (PSB)	8.6V (PSA) & 8	5.0V	192	HRS	77	0
							Total:			0
FAILURE RATE:		MTTF (YRS)	: 40	473	FITS:		2.8			
	D	EVICE HOURS	: 324864	481	FAILS:		0			